

MILITARY SPECIFICATION

SEMICONDUCTOR DEVICE, DIODE, SILICON, SWITCHING,
TYPES 1N643, 1N662 AND 1N663

This amendment forms a part of Military Specification MIL-S-19500/256C,
dated 26 August 1971 and is approved for use by all Departments and
Agencies of the Department of Defense.

Page 1

1.4: Delete type numbers 1N643, 1N662, and 1N663 from t_{rr} column. Add type column and list types 1N643, 1N662, and 1N663.

Page 4

Table I, group A inspection, subgroup 2, capacitance: For type 1N643, delete "V = 175V" in details column and substitute "V = 80 V".

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Table II, group B inspection, subgroup 2 - vibration, variable frequency: Delete entire test.

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Table II, group B inspection, subgroup 3 - vibration, variable frequency: In details column, delete "10 G" and substitute "20 G".

Custodians:

Army - EL
Navy - EC
Air Force - 17

Review activities:

Army - MU, MI
Navy -
Air Force - 11, 80
DSA - ES

User activities:

Army - SM
Navy - CG, MC, OS, AS
Air Force - 19, 15, 13

Preparing activity:

Army - EL

Agent:

DSA - ES

(Project 5961-0364)